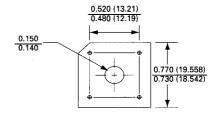
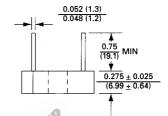
## **KBPC8 ...KBPC810** 8.0A SINGLE - PHASE SILICON BRIDGE

## **Features**

- Surge overload rating 125 Amperes peak
- Low forward voltage drop
- Mounting Position: Any
- Small size; simple installation
- Silver Plated Copper leads
- Ceramic case on BR8 series
- U/L recognized file # 142814

**VOLTAGE RANGE** 50V to 1000 Volts PRV **CURRENT** 8 Amperes





ייט side of case; שופיט side of case; Dimensions in inches and (millimeters)

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified. For capacitive load, derate current by 20%.

		KBPC8005	KBPC801	KBPC802	KBPC804	KBPC806	KBPC808	KBPC810	UNITS
Maximum Recurrent Peak Reverse Voltage		50	100	200	400	600	800	1000	٧
Max RMS Bridge Input Voltage		35	70	140	280	420	560	700	٧
Maximum Average Forward									
Rectified Output Currentat at	T <sub>c</sub> = 100 °C *	8.0							Α
	T <sub>A</sub> = 40 °C**				3.0				Α
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load		125							Α
Maximum Forward Voltage Drop per Bridge element at 4.0A Peak		1.1							٧
Maximum Reverse Current at Rated T <sub>A</sub> = 25 °C		10.0							μА
DC Blocking Voltage per element	T <sub>A</sub> = 100 °C				1.0				mA
Operating Temperature Range T <sub>c</sub>		-55 to + 125							°C
Storage Temperature Range T <sub>A</sub>			-55 to + 150						

NOTES: \* Unit mounted on metal chassis

\*\* Unit mounted on P.C. board



HONEY TECHNOLOGY LTD. (Subsidiary of a company listed on the Hong Kong Stock Exchange)



## **RATING AND CHARACTERISTICS CURVES**

**KBPC8 SERIES** 

